

## 阅读申明

1. 本站收集的数据手册和产品资料都来自互联网，版权归原作者所有。如读者和版权方有任何异议请及时告之，我们将妥善解决。
2. 本站提供的中文数据手册是英文数据手册的中文翻译，其目的是协助用户阅读，该译文无法自动跟随原稿更新，同时也可能存在翻译上的不当。建议读者以英文原稿为参考以便获得更精准的信息。
3. 本站提供的产品资料，来自厂商的技术支持或者使用者的心得体会等，其内容可能存在描述上的差异，建议读者做出适当判断。
4. 如需与我们联系，请发邮件到marketing@iczoom.com，主题请标有“数据手册”字样。

## Read Statement

1. The datasheets and other product information on the site are all from network reference or other public materials, and the copyright belongs to the original author and original published source. If readers and copyright owners have any objections, please contact us and we will deal with it in a timely manner.
2. The Chinese datasheets provided on the website is a Chinese translation of the English datasheets. Its purpose is for reader's learning exchange only and do not involve commercial purposes. The translation cannot be automatically updated with the original manuscript, and there may also be improper translations. Readers are advised to use the English manuscript as a reference for more accurate information.
3. All product information provided on the website refer to solutions from manufacturers' technical support or users the contents may have differences in description, and readers are advised to take the original article as the standard.
4. If you have any questions, please contact us at marketing@iczoom.com and mark the subject with "Datasheets".

# KA5x0365RN-SERIES

## KA5M0365RN, KA5L0365RN Fairchild Power Switch(FPS)

### Features

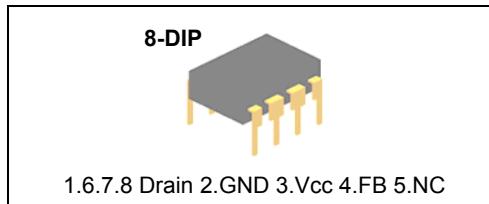
- Precision Fixed Operating Frequency (67/50kHz)
- Low Start-up Current(Typ. 100uA)
- Pulse by Pulse Current Limiting
- Over Current Protection
- Over Voltage Protection (Min. 25V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Auto-Restart Mode

### Applications

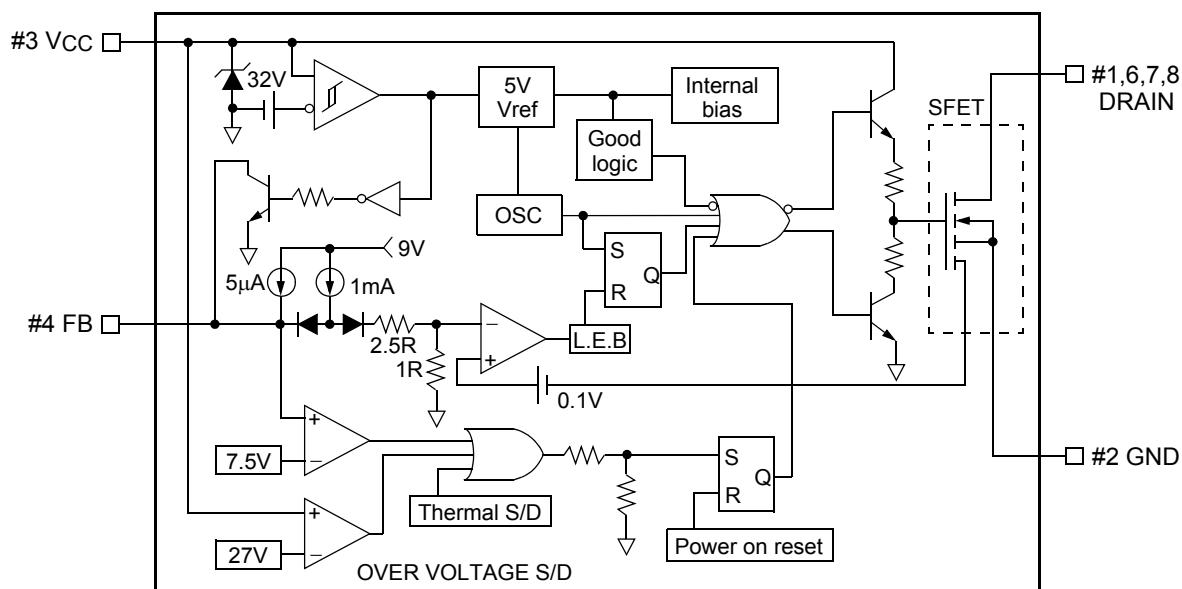
- SMPS for VCR, SVR, STB, DVD & DVCD
- SMPS for Printer, Facsimile & Scanner
- Adaptor for Camcorder

### Description

The Fairchild Power Switch(FPS) product family is specially designed for an off-line SMPS with minimal external components. The Fairchild Power Switch(FPS) consists of a high voltage power SenseFET and a current mode PWM IC. Included PWM controller integrates the fixed frequency oscillator, the under voltage lock-out, the leading edge blanking, the optimized gate turn-on/turn-off driver, the thermal shutdown protection, the over voltage protection, and the temperature compensated precision current sources for the loop compensation and the fault protection circuitry. Compared to a discrete MOSFET and a PWM controller or an RCCsolution, a Fairchild Power Switch(FPS) can reduce the total component count, design size and weight and at the same time increase efficiency, productivity, and system reliability. It has a basic platform well suited for the cost effective design in either a flyback converter or a forward converter



### Internal Block Diagram



Rev.1.0.6

## Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

Characteristic	Symbol	Value	Unit
<b>KA5M0365RN, KA5L0365RN</b>			
Drain-Gate Voltage (RGS=1MΩ)	V <sub>DGR</sub>	650	V
Gate-Source (GND) Voltage	V <sub>GS</sub>	±30	V
Drain Current Pulsed <sup>(1)</sup>	I <sub>DM</sub>	3	ADC
Continuous Drain Current (Ta=25°C)	I <sub>D</sub>	0.42	ADC
Continuous Drain Current (Ta=100°C)	I <sub>D</sub>	0.28	ADC
Single Pulsed Avalanche Energy <sup>(2)</sup>	E <sub>AS</sub>	127	mJ
Maximum Supply Voltage	V <sub>CC,MAX</sub>	30	V
Analog Input Voltage Range	V <sub>FB</sub>	-0.3 to V <sub>SD</sub>	V
Total Power Dissipation	P <sub>D</sub>	1.56	W
	Derating	0.0125	W/°C
Operating Junction Temperature.	T <sub>J</sub>	+160	°C
Operating Ambient Temperature.	T <sub>A</sub>	-25 to +85	°C
Storage Temperature Range.	T <sub>STG</sub>	-55 to +150	°C

**Note:**

1. Repetitive rating: Pulse width limited by maximum junction temperature
2. L = 51mH, starting T<sub>j</sub> = 25°C
3. L = 13µH, starting T<sub>j</sub> = 25°C

## Electrical Characteristics (SenseFET Part)

(Ta = 25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
<b>KA5M0365RN, KA5L0365RN</b>						
Drain-Source Breakdown Voltage	BVDSS	VGS=0V, ID=50µA	650	-	-	V
Zero Gate Voltage Drain Current	IDSS	VDS=Max. Rating, VGS=0V	-	-	50	µA
		VDS=0.8Max. Rating, VGS=0V, TC=125°C	-	-	200	µA
Static Drain-Source on Resistance (Note)	RDS(ON)	VGS=10V, ID=0.5A	-	3.6	4.5	Ω
Forward Transconductance (Note)	gfs	VDS=50V, ID=0.5A	2.0	-	-	S
Input Capacitance	Ciss	VGS=0V, VDS=25V, f=1MHz	-	314.9	-	pF
Output Capacitance	Coss		-	47	-	
Reverse Transfer Capacitance	Crss		-	9	-	
Turn On Delay Time	td(on)	VDD=0.5BVDSS, ID=1.0A (MOSFET switching time is essentially independent of operating temperature)	-	11.2	-	nS
Rise Time	tr		-	34	-	
Turn Off Delay Time	td(off)		-	28.2	-	
Fall Time	tf		-	32	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	VGS=10V, ID=1.0A, VDS=0.5BVDSS (MOSFET switching time is essentially independent of operating temperature)			11.93	nC
Gate-Source Charge	Qgs		-	1.95	-	
Gate-Drain (Miller) Charge	Qgd			6.85		

**Note:**

1. Pulse test: Pulse width ≤ 300µS, duty ≤ 2%

$$2. \quad S = \frac{1}{R}$$

**Electrical Characteristics (Control Part) (Continued)**

(Ta = 25°C unless otherwise specified)

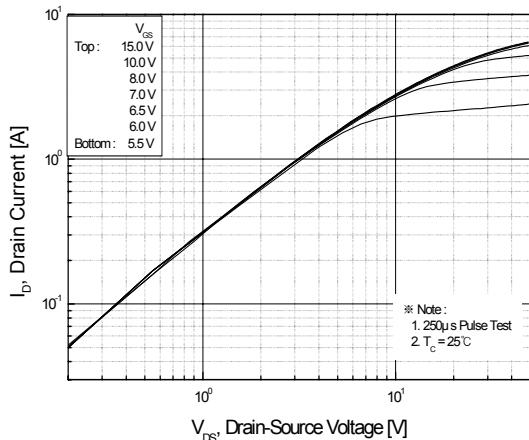
Characteristic	Symbol	Test condition	Min.	Typ.	Max.	Unit
<b>UVLO SECTION</b>						
Start Threshold Voltage	V <sub>START</sub>	V <sub>FB</sub> =GND	14	15	16	V
Stop Threshold Voltage	V <sub>STOP</sub>	V <sub>FB</sub> =GND	8.4	9	9.6	V
<b>OSCILLATOR SECTION</b>						
Initial Accuracy	F <sub>OSC</sub>	<b>KA5M0365RN</b>	61	67	73	kHz
Initial Accuracy	F <sub>OSC</sub>	<b>KA5L0365RN</b>	45	50	55	kHz
Frequency Change With Temperature <sup>(2)</sup>	-	-25°C≤Ta≤+85°C	-	±5	±10	%
Maximum Duty Cycle	D <sub>max</sub>		72	77	82	%
<b>FEEDBACK SECTION</b>						
Feedback Source Current	I <sub>FB</sub>	Ta=25°C, 0V≤V <sub>fb</sub> ≤3V	0.7	0.9	1.1	mA
Shutdown Feedback Voltage	V <sub>SD</sub>	V <sub>fb</sub> ≥6.5V	6.9	7.5	8.1	V
Shutdown Delay Current	I <sub>delay</sub>	Ta=25°C, 5V≤V <sub>fb</sub> ≤V <sub>SD</sub>	4	5	6	μA
<b>REFERENCE SECTION</b>						
Output Voltage <sup>(1)</sup>	V <sub>ref</sub>	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability <sup>(1)(2)</sup>	V <sub>ref</sub> /ΔT	-25°C≤Ta≤+85°C	-	0.3	0.6	mV/°C
<b>CURRENT LIMIT(SELF-PROTECTION)SECTION</b>						
Peak Current Limit	I <sub>OVER</sub>	Max. inductor current	1.89	2.15	2.41	A
<b>PROTECTION SECTION</b>						
Over Voltage Protection	V <sub>OVP</sub>	V <sub>CC</sub> ≥24V	25	27	29	V
Thermal Shutdown Temperature (T <sub>j</sub> ) <sup>(1)</sup>	T <sub>SD</sub>	-	140	160	-	°C
<b>TOTAL STANDBY CURRENT SECTION</b>						
Start-up Current	I <sub>START</sub>	V <sub>CC</sub> =14V	-	100	170	μA
Operating Supply Current (Control Part Only)	I <sub>OP</sub>	V <sub>CC</sub> ≤28	-	7	12	mA

**Note:**

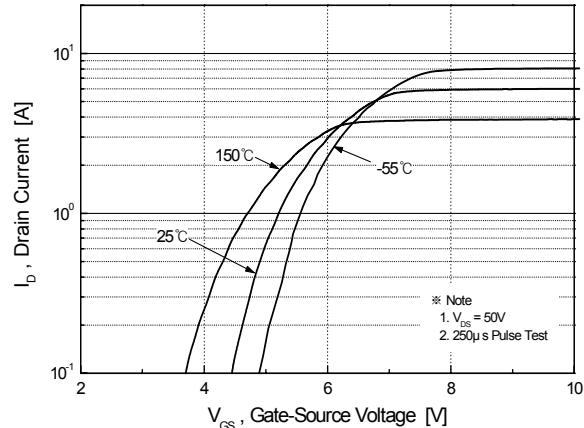
1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS(water test) process

## Typical Performance Characteristics(SenseFET part) (Continued)

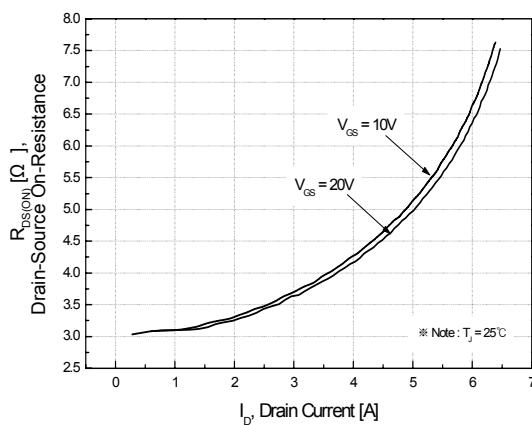
(KA5M0365RN, KA5L0365RN)



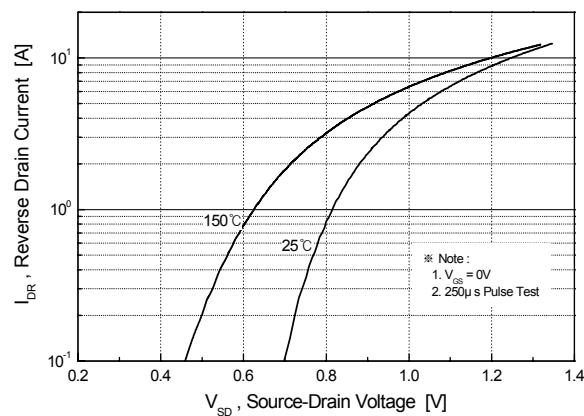
**Figure 1. Output Characteristics**



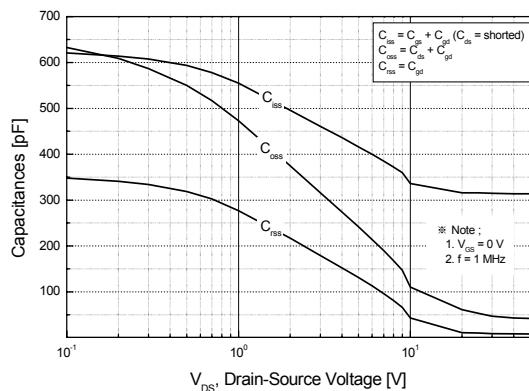
**Figure 2. Transfer Characteristics**



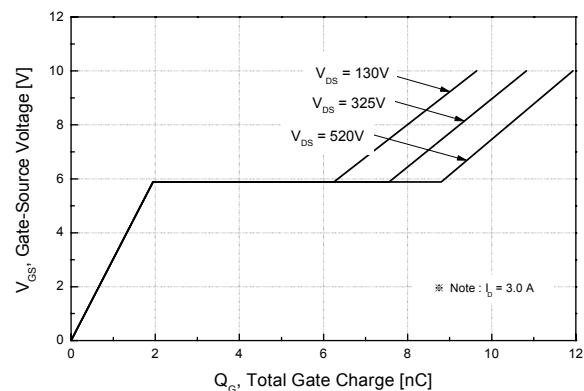
**Figure 3. On-Resistance vs. Drain Current**



**Figure 4. Source-Drain Diode Forward Voltage**



**Figure 5. Capacitance vs. Drain-Source Voltage**



**Figure 6. Gate Charge vs. Gate-Source Voltage**

## Typical Performance Characteristics (Continued)

( KA5M0365RN, KA5L0365RN )

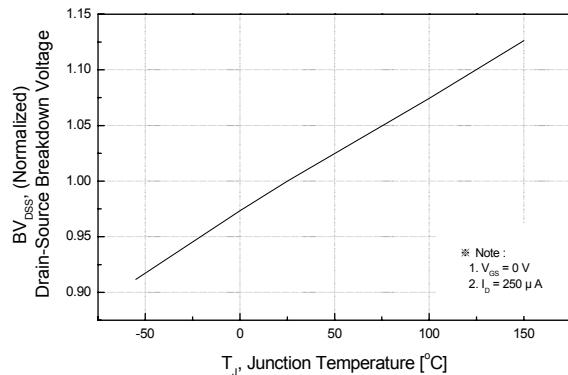


Figure 7. Breakdown Voltage vs. Temperature

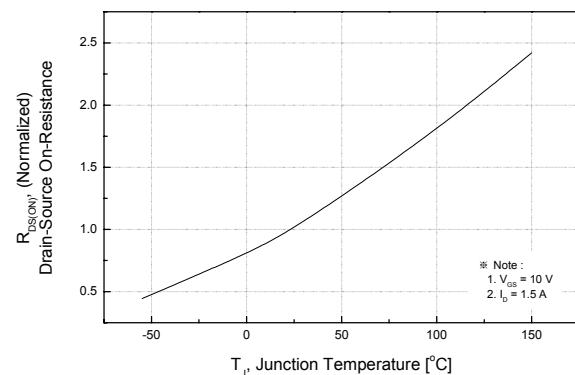


Figure 8. On-Resistance vs. Temperature

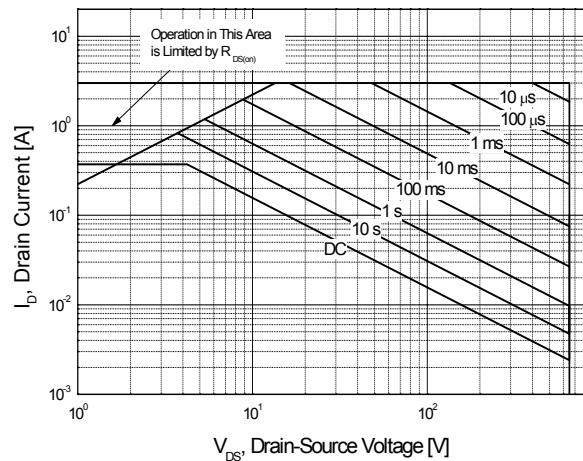


Figure 9. Max. Safe Operating Area

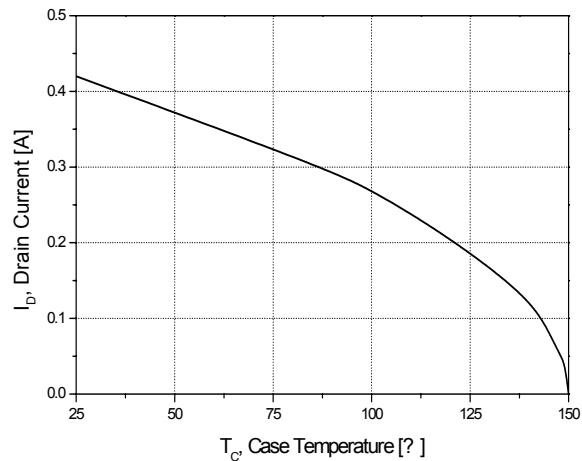


Figure 10. Max. Drain Current vs. Case Temperature

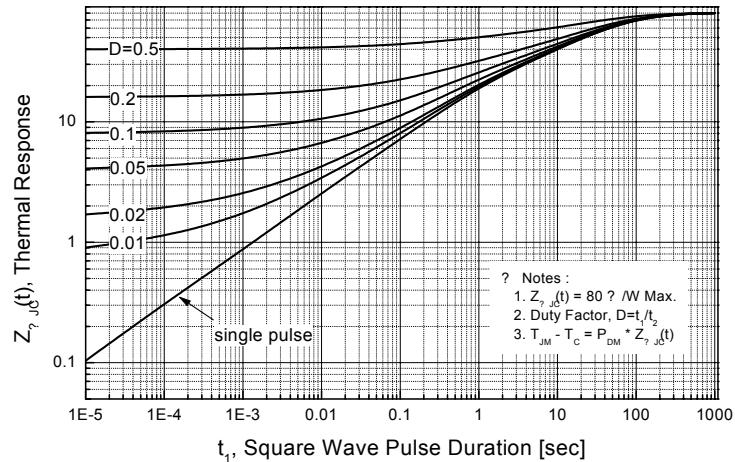


Figure 11. Thermal Response

## Typical Performance Characteristics (Control Part) (Continued)

(These characteristic graphs are normalized at  $T_a = 25^\circ\text{C}$ )

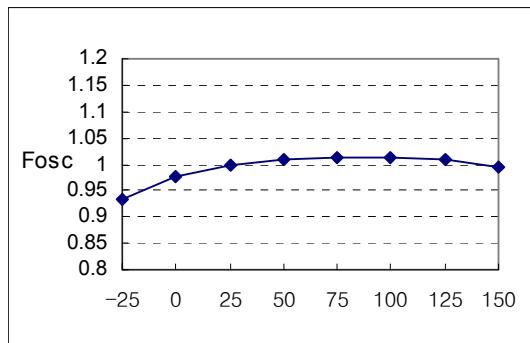


Figure 1. Operating Frequency

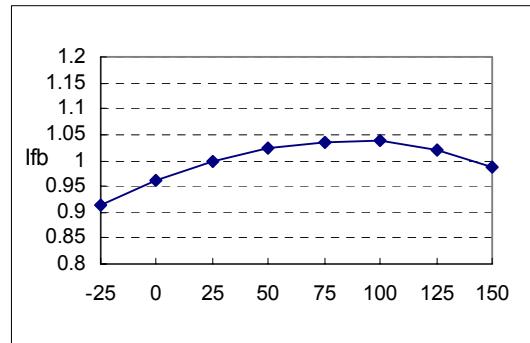


Figure 2. Feedback Source Current

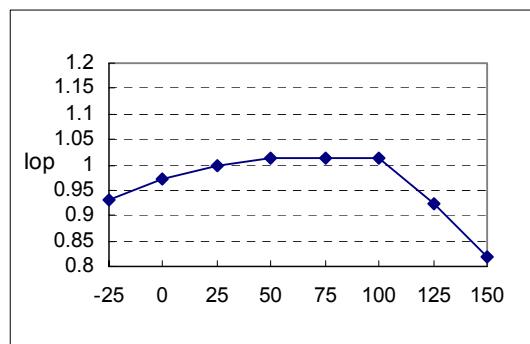


Figure 3. Operating Supply Current

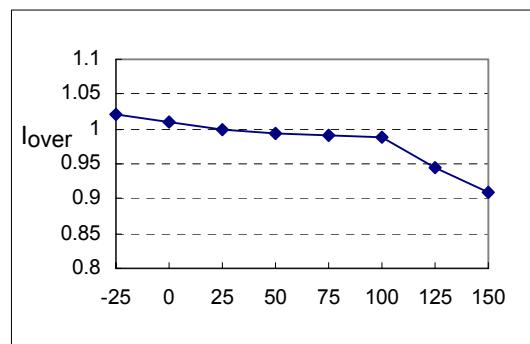


Figure 4. Peak Current Limit

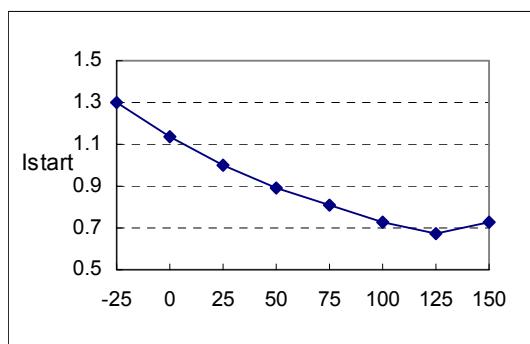


Figure 5. Start up Current

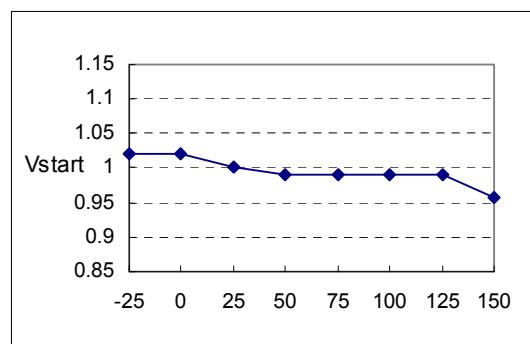


Figure 6. Start Threshold Voltage

## Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at  $T_a = 25^\circ\text{C}$ )

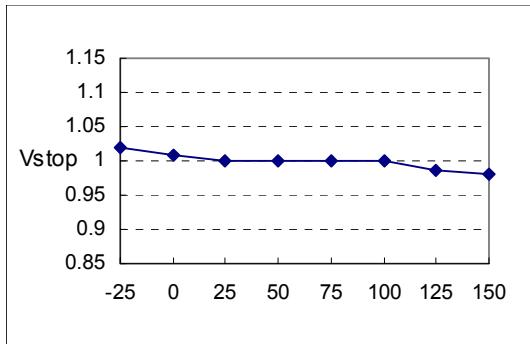


Figure 7. Stop Threshold Voltage

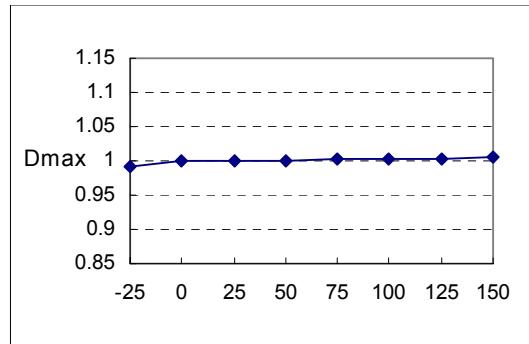


Figure 8. Maximum Duty Cycle

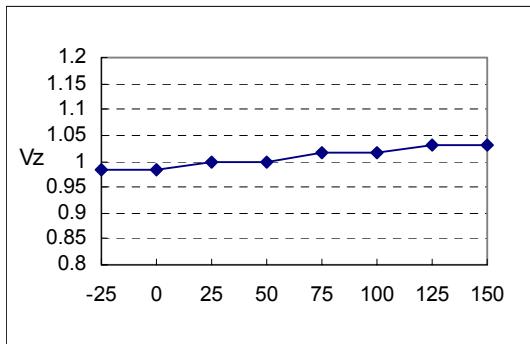


Figure 9. VCC Zener Voltage

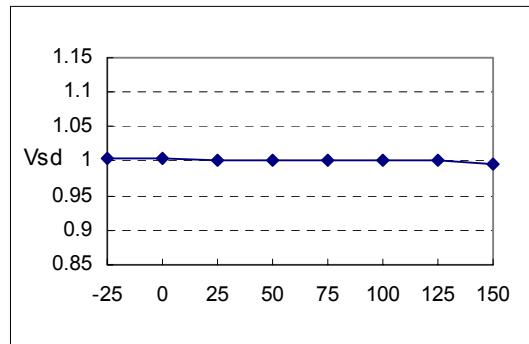


Figure 10. Shutdown Feedback Voltage

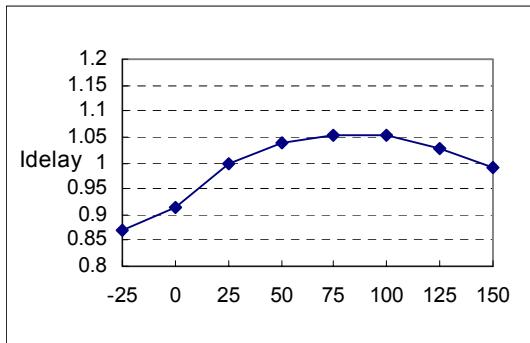


Figure 11. Shutdown Delay Current

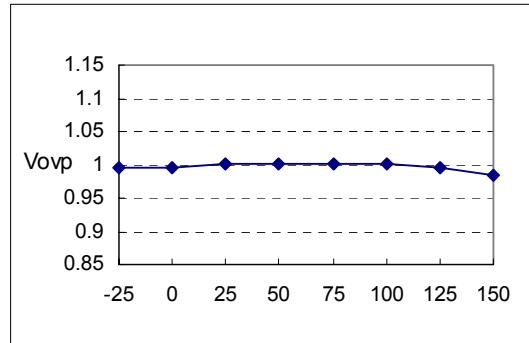


Figure 12. Over Voltage Protection

## Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at  $T_a = 25^\circ\text{C}$ )

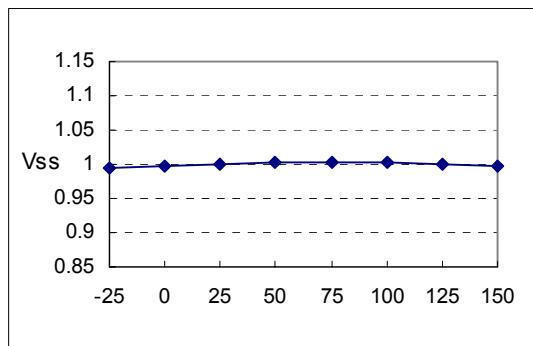


Figure 13. Soft Start Voltage

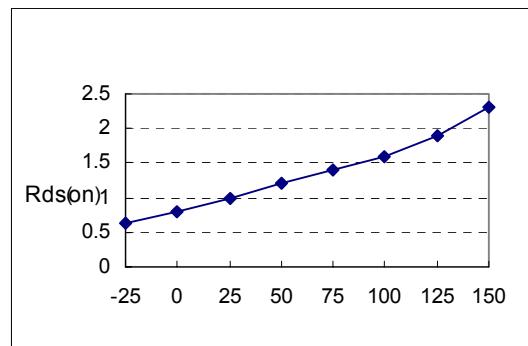
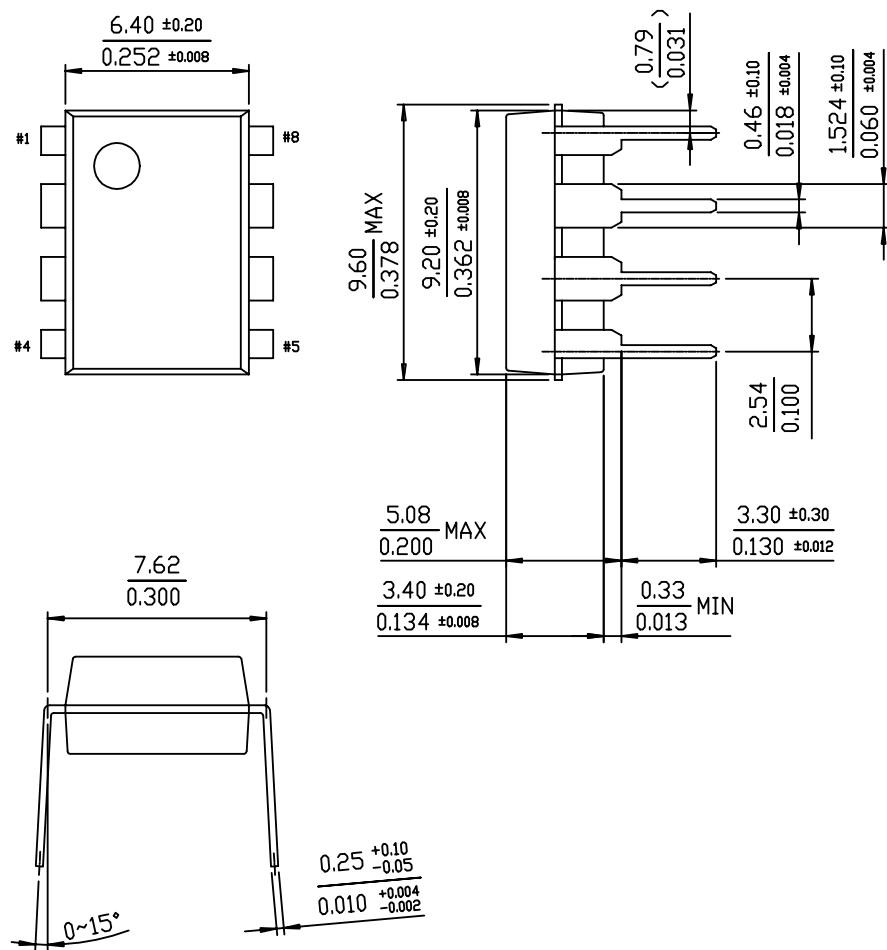


Figure 14. Static Drain-Source on Resistance

## Package Dimensions

### 8-DIP



## Ordering Information

Product Number	Package	Marking Code	BVDSS	Fosc	RDS(on)
KA5M0365RN	8-DIP	5M0365R	650V	67kHz	3.6Ω
KA5L0365RN	8-DIP	5L0365R	650V	50kHz	3.6Ω

#### **DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

#### **LIFE SUPPORT POLICY**

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.